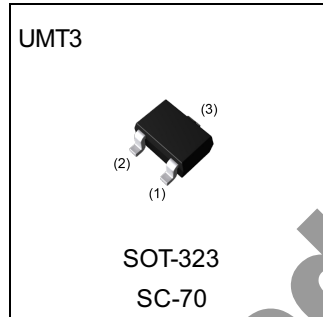


Parameter	Value
V_{CEO}	60V
I_C	500mA

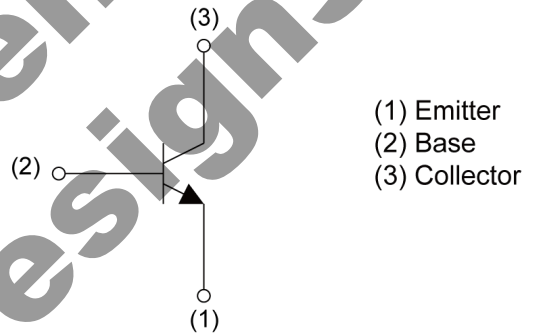
●Outline



●Features

- 1)High speed switching.
(T_f :Typ.:80ns at $I_C=500mA$)
- 2)Low saturation voltage, typically
(Typ.:150mV at $I_C=100mA$, $I_B=10mA$)
- 3)Strong discharge power for inductive load and capacitance load.
- 4)Complements the 2SA2088.

●Inner circuit



●Application

LOW FREQUENCY AMPLIFIER, HIGH SPEED SWITCHING

●Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
2SC5876	UMT3	2021	T106	180	8	3000	VS

● **Absolute maximum ratings** ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Values	Unit
Collector-base voltage	V_{CBO}	60	V
Collector-emitter voltage	V_{CEO}	60	V
Emitter-base voltage	V_{EBO}	6	V
Collector current	I_{C}	500	mA
	I_{CP}^{*1}	1.0	A
Power dissipation	P_{D}^{*2}	200	mW
Junction temperature	T_{j}	150	$^\circ\text{C}$
Range of storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

● **Electrical characteristics** ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Collector-base breakdown voltage	BV_{CBO}	$I_{\text{C}} = 100\mu\text{A}$	60	-	-	V
Collector-emitter breakdown voltage	BV_{CEO}	$I_{\text{C}} = 1\text{mA}$	60	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	$I_{\text{E}} = 100\mu\text{A}$	6	-	-	V
Collector cut-off current	I_{CBO}	$V_{\text{CB}} = 40\text{V}$	-	-	1	μA
Emitter cut-off current	I_{EBO}	$V_{\text{EB}} = 4\text{V}$	-	-	1	μA
Collector-emitter saturation voltage	$V_{\text{CE(sat)}}$	$I_{\text{C}} = 100\text{mA}, I_{\text{B}} = 10\text{mA}$	-	150	300	mV
DC current gain	h_{FE}	$V_{\text{CE}} = 2\text{V}, I_{\text{C}} = 50\text{mA}$	120	-	390	-
Transition frequency	f_{T}^{*3}	$V_{\text{CE}} = 10\text{V}, I_{\text{E}} = -100\text{mA}, f = 100\text{MHz}$	-	300	-	MHz
Output capacitance	C_{ob}	$V_{\text{CB}} = 10\text{V}, I_{\text{E}} = 0\text{mA}, f = 1\text{MHz}$	-	5	-	pF
Turn-On time	t_{on}^{*3}	$I_{\text{C}} = 500\text{mA}, I_{\text{B1}} = 50\text{mA}$	-	70	-	ns
Storage time	t_{stg}^{*3}	$I_{\text{B2}} = -50\text{mA}, V_{\text{CC}} \approx 25\text{V}$	-	130	-	ns
Fall time	t_{f}^{*3}	$R_{\text{L}} = 50\Omega$ See test circuit	-	80	-	ns

hFE values are classified as follows :

rank	Q	R	-	-	-
hFE	120-270	180-390	-	-	-

*1 $P_{\text{w}} = 10\text{ms}$

*2 Each terminal mounted on a reference land.

*3 Pulsed

● Electrical characteristic curves ($T_a = 25^\circ\text{C}$)

Fig.1 Ground Emitter Propagation Characteristics

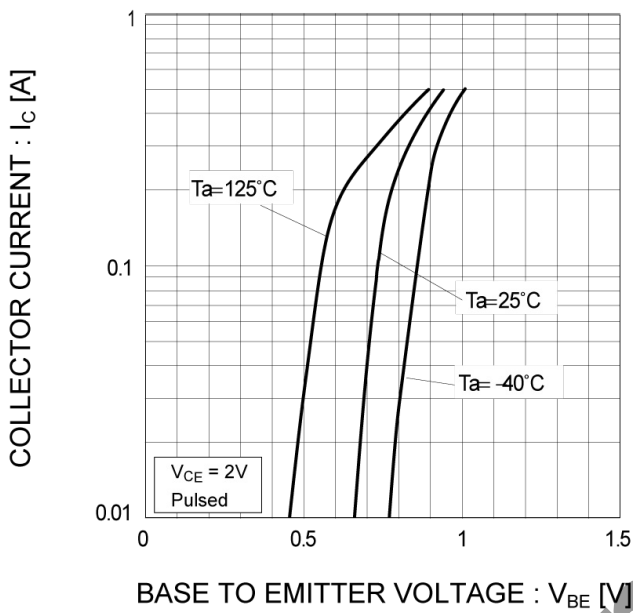


Fig.2 Typical Output Characteristics

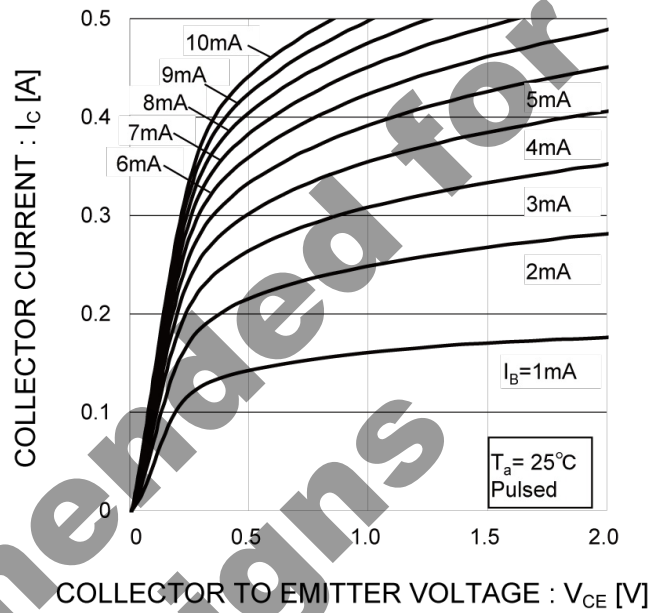


Fig.3 DC Current Gain vs. Collector Current (I)

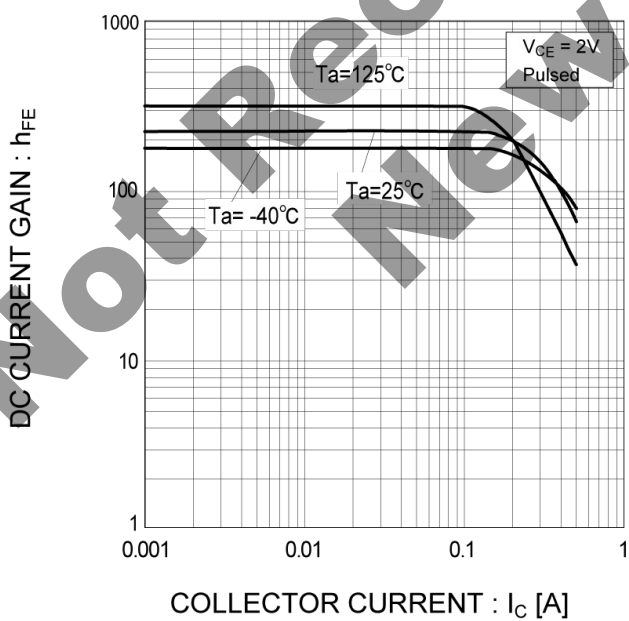
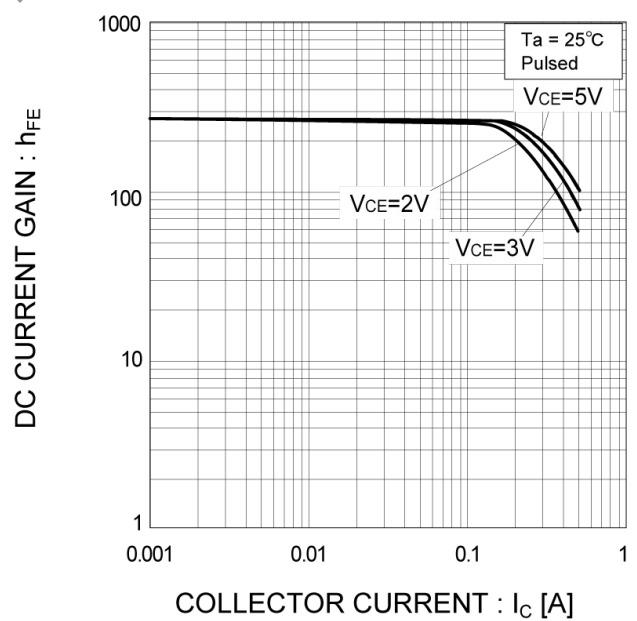


Fig.4 DC Current Gain vs. Collector Current (II)



● Electrical characteristic curves ($T_a = 25^\circ\text{C}$)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

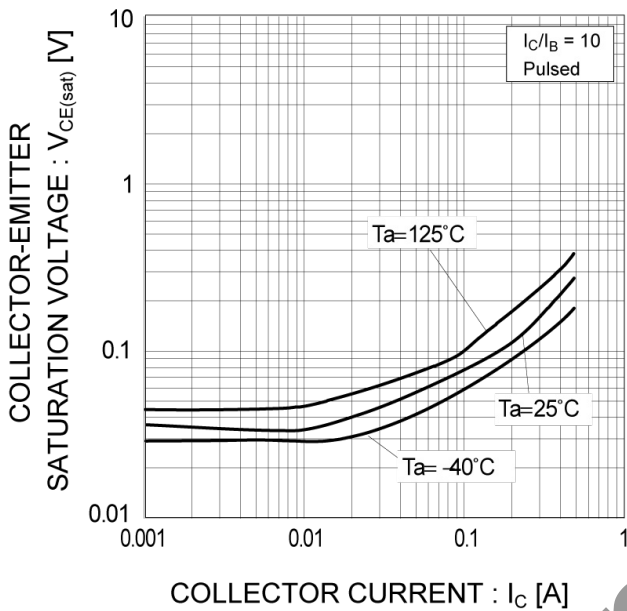


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II)

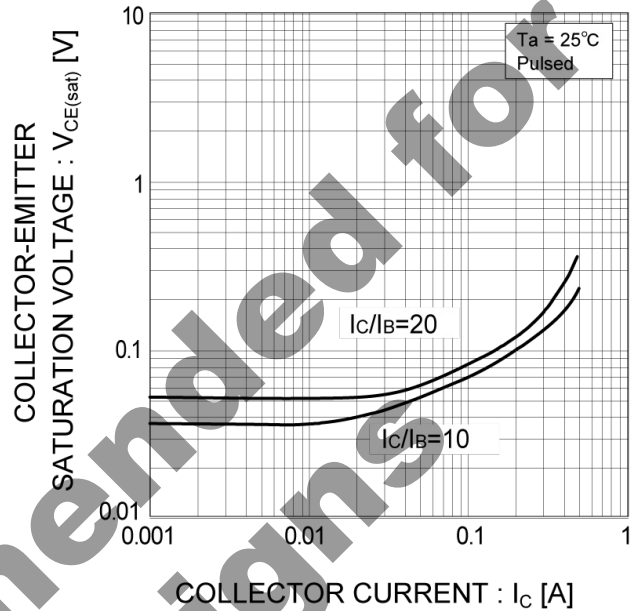


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

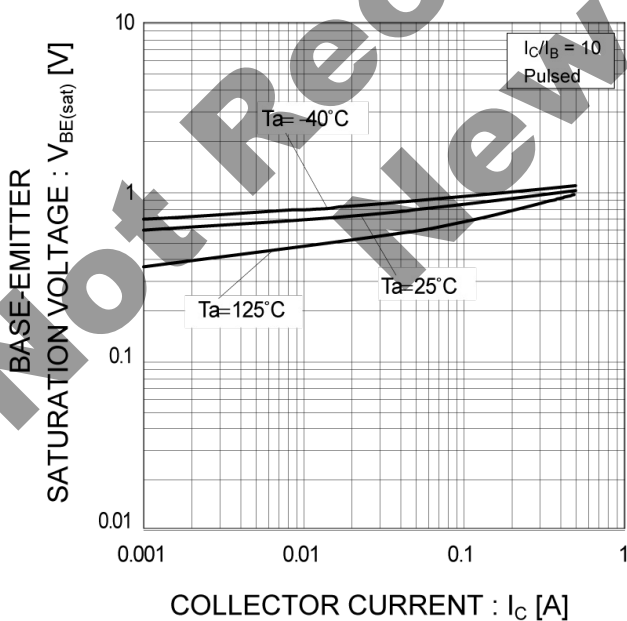
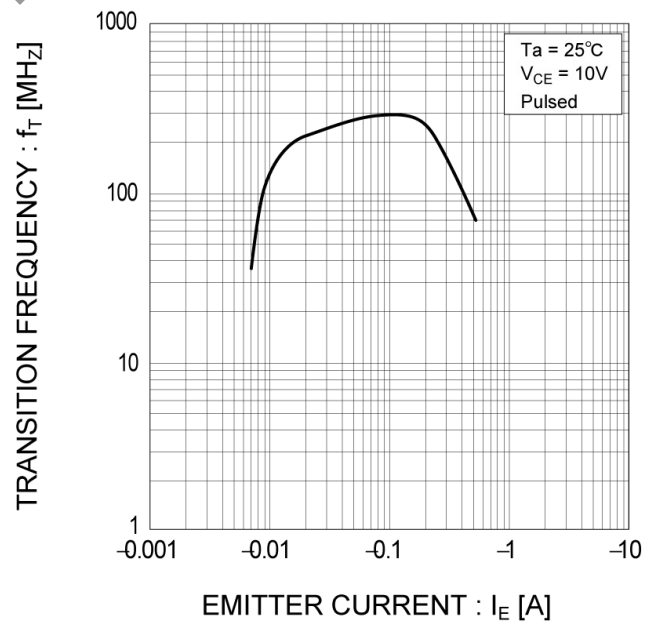


Fig.8 Transition Frequency



●Electrical characteristic curves($T_a = 25^\circ\text{C}$)

Fig.9 Collector output Capacitance

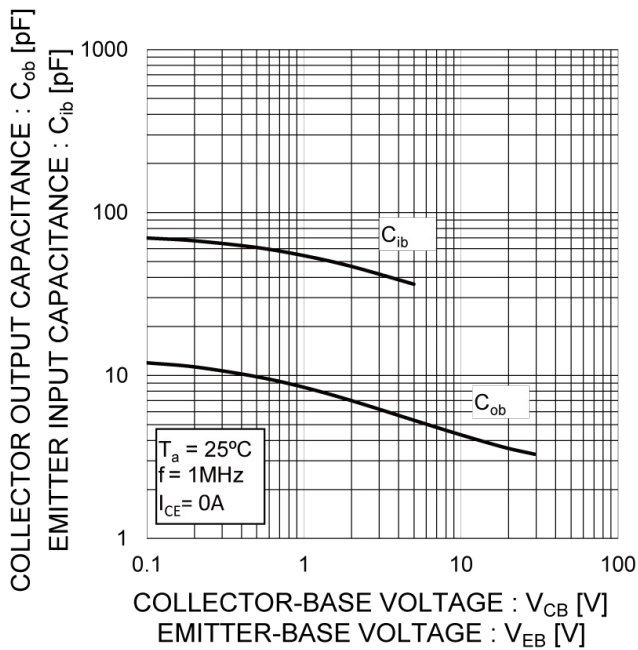
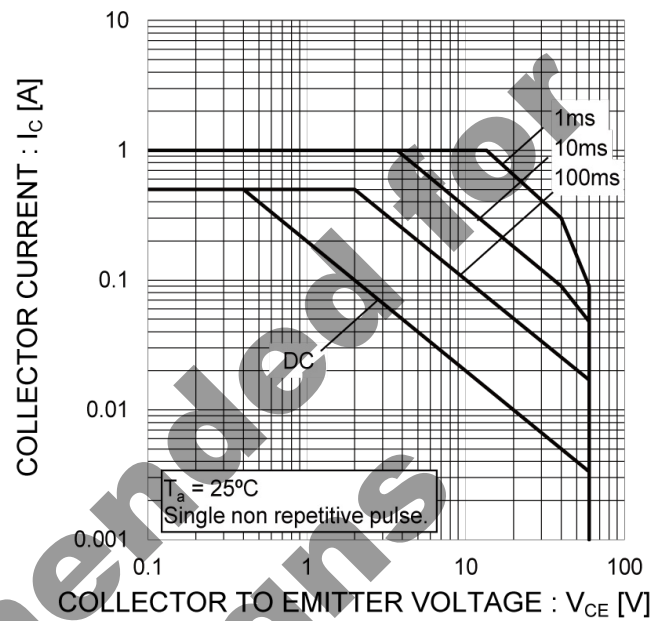
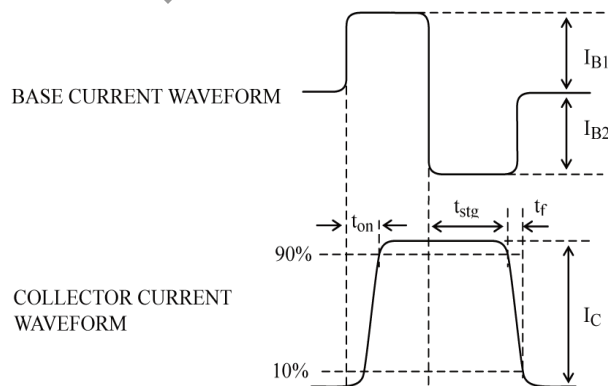
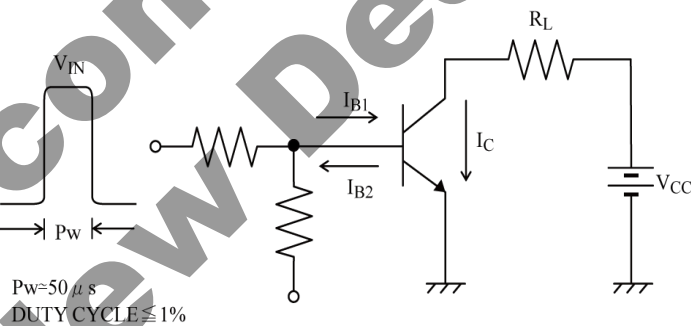


Fig.10 Safe Operating Area

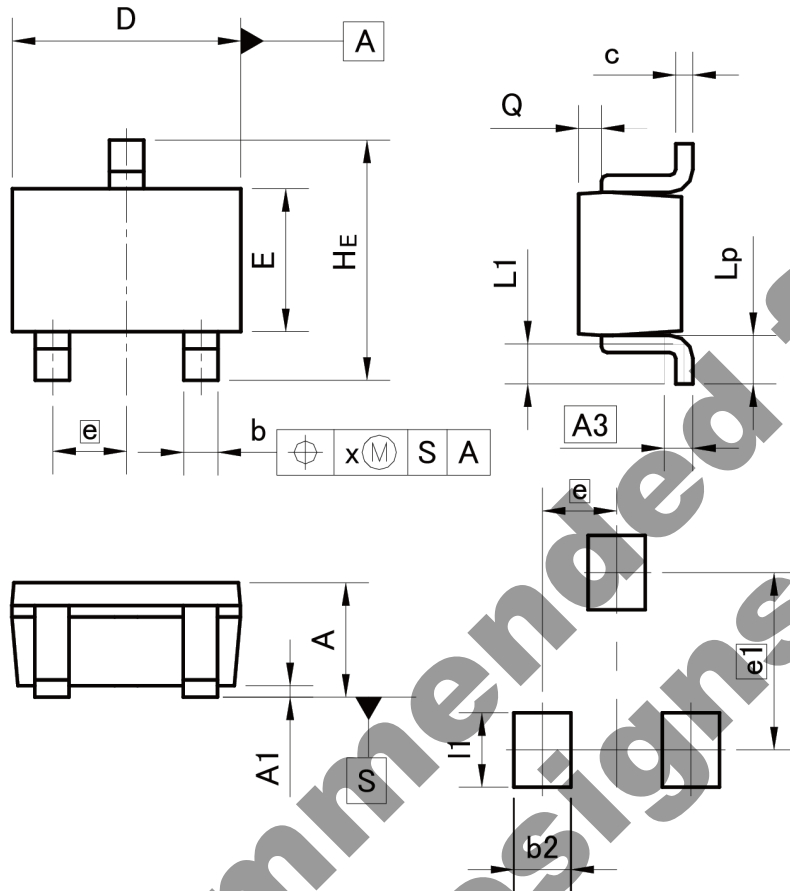


SWITCHING TIME TEST CIRCUIT



●Dimensions

UMT3



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.80	1.00	0.031	0.039
A1	0.00	0.10	0.000	0.004
A3	0.25		0.010	
b	0.15	0.30	0.006	0.012
c	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
e	0.65		0.026	
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.020
Lp	0.25	0.55	0.010	0.022
Q	0.10	0.30	0.004	0.012
x	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.50	-	0.020
e1	1.55		0.061	
l1	-	0.65	-	0.026

Dimension in mm/inches

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